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FERRAVCE

COMPOUND SEMICONDUCTOR SYSTEMS DIVISION

ELECTRONIC COMPONENTS(ELECOM) GROUP

SHARP CORPORATION

# **SPECIFICATIONS**

# DEVICE SPECIFICATION FOR

# LIGHT EMITTING DIODE

MODEL No.

# GM1WA55311A

CUSTOMERS' APPROVAL

Date

By

# PRESENTED

Date -Dec. 20. 07

By 1.11

S. Yokota Department General Manager LED Business Development Center Compound Semiconductor Systems Division Electronic Components (ELECOM) Group SHARP CORPORATION

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(1) <u>This</u>	s products is designed for u			, · <u> </u>	
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	arding interpretation of the		and the more are any que		
3. Please contact	t and consult with a Sharp s	sales representative for a	ny questions about this j	product.	



# **GM1WA55311A** specification

#### 1. Application

SHARE

This specification applies to the light emitting diode device Model No. GM1WA55311A. [InGaN/SiC blue, InGaN/SiC green, AlGaInP/GaAs red : RGB 3 color chip LED device] This product is designed for various kinds of general indication devices.

2. External dimensions and equivalent circuit ......Refer to Page3.

3. Ratings and characteristics ......Refer to Page4~8.

3-1. Absolute maximum ratings

3-2. Electro-optical characteristics

3-3. Derating Curve

3-4. Characteristics Diagram (TYP.)

4. Reliability ••••••Refer to Page9.

4-1. Test items and test conditions

4-2. Failure criteria

5-1. Applied standard

5-2. Sampling method

5-3. Inspection items and defect criteria

6. Supplements ·······Refer to Page10~13.

6-1. Taping

6-2. Packing

6-3. Label

6-4. Luminous intensity rank table

6-5. Information on environmental impact substances

7. Precautions ······Refer to Page14~15.

7-1. General handling

- 7-2. Soldering
- 7-3. Cleaning



PWB: Glass epoxy	
Resin: Epoxy resin	Au plated

mm

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#### 3. Ratings and characteristics

3-1. Absolute maximum ratings

			<u>I</u> :	RT	GI	MIWA555IIA	
ARP Ratings and characteristics						AGNIC	-
. Absolute maximum ratings				(T	c=25℃)		Francis
Prameter	Symbol	BC (Blue)	Rating GC (Green)	JJ (Red)	Unit		
Power dissipation	Р		45.5		mW		
Forward current(*1)	I <sub>F</sub>	10	10	10	mA		
Peak forward current (* 2)	I <sub>FM</sub>	20	20	20	mA	,	
Denoting factor	DC	0.13	0.13	0.13	mA/℃		
Derating factor	Pulse	0.27	0.27	0.27	mA/℃		
Reverse voltage	V <sub>R</sub>		5.0		V		
Operating temperature	Tc(*3)	-2	$20 \sim +80$		°C		
Storage temperature	Tstg	-4	$0 \sim +100$		°C		
Soldering temperature(*4)	Tsol		290		Ĵ		

(\*1) Rating is prescribed by each color chip. In operating three color chips simultaneously, be sure not

to exceed the rating of power dissipation.

(\*2) Duty ratio=1/10, Pulse width=0.1ms

(\*3) As for case temperature, please refer to Page 3/15, Outline dimensions and terminal connections

(\*4) Each terminal must be soldered with the soldering iron of capacity below 30W within 3 seconds under 290°C.

3-2	. Electro-optical characteristics			(Tc=25°C				l
. '	Parameter	Symbol	Color	Conditions	MIN.	TYP.	MAX.	Unit
	· ·		BC	T ·	· -	2.9	3.2	-
	Forward voltage	V <sub>F</sub>	GC	I <sub>F</sub> =5mA	-	3.0	3.3	V
			JJ	·	-	1.9	2.3	
•			BC	-	10	23	47	
	Luminous intensity (* 5)	Iv	GC	I <sub>F</sub> =5mA	36	70	190	mcd
			11	-	9.8	20	51	
	, /		BC		470	473	480	
	Dominant wavelength (*6)	λd	GC	I <sub>F</sub> =5mA	516	527	540	nm
			JJ		610.5	616	623.5	
			BC	•	-	23	-	
	Spectrum radiation bandwidth	$\Delta \lambda$	GC	I <sub>F</sub> =5mA	-	35	· -	nm
			JJ		-	18	-	
	· · · · · · · · · · · · · · · · · · ·		BC		-	-	100	
	Reverse current	I <sub>R</sub>	GC	V <sub>R</sub> =4V	-	-	100	μA
		· · ]	JJ	1	-		100	

(\*5)Measured by SHARP EG&G MODEL550(Radiometer/Photometersystem) (after 20ms drive)(Tolerance:±15%) (\*6) Measured by Ohtsuka electronics MODEL MCPD-2000 (after 20ms drive)

The values of this table are the typical data classified under the conditions in the above table and are not guaranteed data. (\*7) Refer to 6-4. Luminous intensity rank table.

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3-3. Derating Curve • BC, GC, JJ







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Peak Forward Current vs. Duty Ratio







(\*)Characteristics data above are typical data and are not guaranteed data.

MODEL No. Page GM1WA55311A TEFERENCI 7/15 SHARP 3-4. Characteristics Diagram (TYP.) 3-4-2. Characteristices Diagram of GC (Tc=25°C)  $(I_F = 5mA)$ 1 000 100 Relative Luminous Intensity (%) Forward Current I<sub>F</sub> (mA) 10 100 1 10 0.1 -20 0 60 20 40 80 1.5 2. 0 2.5 3.0 3.5 4.0 Case Temperature Tc(℃) Forward Voltage V<sub>F</sub> (V) Forward Current vs.Forward Voltage Relative Luminous Intensity vs. Case Temperature

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1 K

Forward Current I<sub>F</sub> (mA)

1

Relative Luminous Intensity vs. Forward Current

10

100

(\*)Characteristics data above are typical data and are not guaranteed data.





Relative Luminous Intensity vs. Forward Current

(\*)Characteristics data above are typical data and are not guaranteed data.

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## 4. Reliability

·			GM1V	VA5531	IA	9
	RP eliability The reliability of p	roduct shall be satisfied with the contents listed below.	- Al		CE	
<u>4-1.</u>	Test items and test	conditions	Confi	dence lev	el: 90%	nai, J
No.	Test items	Test conditions	Samples	Defective	LTPD	
			n	С	<u>(%</u> )	
1	Temperature	-40 $^{\circ}C(30 \text{ min})$ ~+100 $^{\circ}C(30 \text{ min})$ , 30 times				
	cycle	· · · · · · · · · · · · · · · · · · ·	22	0	10	
2	High temp and high	Tstg=+60 °C, RH=90 %, t=500 h				
	humidity storage		22	0	10	
3	High temperature	$Tstg = +100^{\circ}C, t = 500 h$				
L	storage		22	0	10	
4	Low temperature	Tstg=-40℃, t=500 h				
	·storage		22	0	10	
5	Operating test	Tc=25 °C, $I_{\rm F}$ =5mA, t=500 h				
		(3 color-chip simultaneous operation)	22	0	10	
6	Mechanical shock	Tc=25 °C, 15 000 m/s <sup>2</sup> , 0.5 ms				
		X·Y·Z directions, 3 times respectively	11	· 0	20	
7	Variable frequency	Tc=25 °C, 200 m/s <sup>2</sup> , 100 $\sim$ 2 000 $\sim$ 100 Hz / sweep for 4 min.		н. С		
	vibration	X·Y·Z directions, 4 times respectively	11	0	20	
8	Soldering heat	Twice, refer to Page 14				
			11	0	20	
9	Solder ability	240±5℃, 5±1s				
	(Dip Method) (*1)	(Solder/Flux : M705/ESR250 (SENJU METAL INDUSTRY)	) 11	0	20	

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### 4-2. Failure criteria (\*2)

Temperature cycle, High temp and high humidity storage, High temperature storage,

Low temperature storage, Operating test, Mechanical shock test, Variable frequency vibration, Soldering heat

No.	Parameter	Symbol	Failure judgment criteria (*3)
1	Forward voltage	V <sub>F</sub>	$V_F > U.S.L \times 1.2$
2	Reverse current	I <sub>R</sub>	$I_R > U.S.L \times 2.0$
3	Luminous intensity	I <sub>V</sub>	Iv < Initial value $\times$ 0.5, Iv > Initial value $\times$ 2.0

# (\*1): Solderability failure criteria

•Bottom parts of the product : Refer to the following figure ( Solderability judgment area ). If more than 90% of shaded portions are not soldered, it is to be failure.



(\*2): Measuring conditions accord with the specification. (\*3): U.S.L. stands for Upper Specification Limit.

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5. Quality level

5-1. Applied standard ISO2859-1

5-2. Sampling method

A single sampling plan, normal inspection level S-4.

5-3. Inspection items and defect criteria

No.	Inspection items	Criteria	Defect	AQL
1	Radiation color	Different from the color prescribed in the page 4/15	Major	0.10/
2	Taping	Inserted in wrong direction	defect	0.1%
3	Electro-optical characteristics	Not satisfied with specification value (page 4/15), for $V_{F}$ , $I_{R}$ , $I_{V}$ .		
4	Outline dimensions	Not satisfied with specification value (page 3/15), for outline dimension.	Minor defect	0.4%
5		More than $\varphi 0.6mm$ of foreign substances, flaws, bubbles. Resin burr which is over dimension tolerance. The defect of resin and the terminals, which are over 0.4mm		

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6. Supplements

6-1. Taping

6-1-1. Shape and dimension of tape (Ref.)



Parameter		Symbol	Dimension [mm]	Remarks
Concave square Vertical		A	1.9	Dimension excluded corner R at the bottom
hole for parts	Horizontal	В	1.9	inside.
insertion	Pitch	P1	.4.0	
Round sprocket	Diameter	D <sub>0</sub>	1.5	
hole	Pitch	P <sub>0</sub>	4.0	Accumulated error ±0.5mm/10 pitch
	Position	E	1.75	Distance between the edge of the tape and the center of the hole
Center to center	Vertical	P <sub>2</sub>	2.0	Distance between center line of the concave
distance	Horizontal	F	3.5	square hole and round sprocket hole
Cover tape	Horizontal	W1	5.5	
Cover tape	Thickness	t3	0.1	
Carrier tape	Width	Wo	8.0	
Carrier tape	Thickness	t	0.2	
Thickness of entir	e unit	t <sub>2</sub>	1.0	With cover tape and carrier tape combined

\*Both Carrier tape and Cover tape prevent static electricity.

6-1-2. Shape and dimension of reel (Ref.)



	Parameter		Symbol	Dimensions(mm)	Remarks
	Diameter       Flange     Thickness		A	φ180	
Flange			t	1.5	· · · · · · · · · · · · · · · · · · ·
	Inner space direction		W	10	Dimension of shaft core
	External diameter		В	φ60	
Hub	Spindle ho	le diameter	С	φ13	
muo	Key slit	Width	E	2	
		Depth	U	4.5	
Notatio	on for part na	ame etc.	Labeled or	1 the side of	the flange. (part name, quantity, LOT No.)
X Mater	rial : ReelF	Polystyrene			· · · · · · · · · · · · · · · · · · ·



<sup>(2)</sup>The quantity of the products lacking should be less than 0.1% of total product quantity.

③Products should be easily taken out.

④Products should not be attached to the cover tape when it peeled off.

### 6-2. Packing

In order to avoid the absorption of humidity while transport and storage, the devices are kept in moisture proof aluminum packages.



#### 6-2-1.Storage conditions

Temperature : 5 to 30 ℃ Relative humidity : 60% or less

- 6-2-2. Handling method after opening the packages
  - ①Please give the soldering process under the conditions mentioned below within 7 days after opening the packages. Temperature : 5 to 30 ℃, Relative humidity : 60% or less
  - ②In case that the devices are not used for a long time after opened, the storage in a dry box is recommended. It is also recommended to repack the devices with a desiccative by the sealer and keep them under the same storage conditions as 6-2-1. (within 30days)
  - ③ Please give the following baking treatment before soldering if the blue color of the silica gel indicator changes its color or fades.

(Recommended condition) •In taping

Temperature: 60 °C to 65 °C, Time: 36 to 48 hours

- ·In individual (on PCB or metallic tray)
- Temperature: 100 °C to 120 °C, Time: 2 to 3 hours



# 2) RANKOOO : (Left) Red (Middle)Green (Right)Blue

6-4. Luminous i BC	intenisyt rank i	autex			(Tc=25°C
Rank	Lumi	nous inten	sity	Unit	Condition
A	10	~	25	L	I <sub>F</sub> =5mA
В	19	~	47	mcd	IF-JIIIA
				<i>.</i>	(Tolerance ; $\pm 15\%$ )
GC		· · · · · · · · · · · · · · · · · · ·	· · · · · · · · · · · · · · · · · · ·		(Tc=25°C
Rank	Lumi	nous intens	sity	Unit	Condition
Α	36	~	77	mcd	
B	56	~	121		I <sub>F</sub> =5mA
С	89	~	190		
					(Tolerance ; $\pm 15\%$ )
IJ					(Tc=25℃
Raņk	Lumi	nous intens	sity	Unit	Condition
Α	9.8	~	26	med	I <sub>F</sub> =5mA
В	19.0	~	51	mcd	1 <sup>E</sup> =2111 <sub>W</sub>
XQuanity-ratio	of the ranks a	re decided	by Sharp.		(Tolerance ; ±15%)

6-5. Information on environmental impact substances

#### 6-5-1. RoHS compliant product

This product is manufactured in accordance with RoHS directive. (Applied to the products manufactured in and after April of 2001.)

#### 6-5-2. Ozone Depleting Substances

- (1) This product doesn't contain the following Ozone Depleting Substances.
- (2) This product doesn't have a production line whose process requires the following Ozone Depleting Substances.

Restricted substances: CFCs, Halones, CCl<sub>4</sub>, 1, 1, 1-Trichloroethane (Methyl chloroform)

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IODEL N

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# SHARP

- 7. Precaitions
  - 7-1. General handling
- TEFERENCE • In designing a circuit, please make sure not to give reverse voltage to the LEDs at any time • Since the LEDs are very small, they are easily damaged by external stress.

Please be careful in handling the products not to apply stress to them after the assemblies.

•Please avoid locating the conductor on the top of the resin, since the Au wire is near under the resin surface.

•The LEDs can be damaged by static electricity or surge voltage. Please equip yourself with

a wrist band or anti-electricity gloves in handling the LEDs.

Also, make sure that all the devices and equipments must be grounded.

·Materials with high thermal conductivity is used for this device in order to allow generated heat to escape effectively out of the LED. Avoid locating other heat sources (ex. resistance, etc.) near the LED on the circuit board. Those heat sources will damage the devices .

Therefore, the circuit board should be designed in a way that other heat sources are located away from the LED and that the heat generated from the circuit board can easily escape out of the circuit board.

#### 7-2. Soldering

7-2-1.Reflow

(1) Please handle the products under the condition that package temperature is followed by the reflow profile. (refer to the Fig. below)

However, since external stress and force may cause damage on the internal packages even when it is under the profile condition (refer to the Fig. below), please pay attention to the condition of your reflow machine.

- (2) In case of giving reflow process twice, the second reflow process should be given as soon as possible after the first one. (Storage in a dry box is recommended between the processes.)
- (3) N2 Reflow is also available.
- (4) Temperature profile



As for Reflow Soldering Temperature Profile, in order to maintain the products quality, it is recommended that the peak temperature should be lower, and cool down should be taken longer, and that the gradient of cooldown temperature should be as low as possible.

Moreover, since the thermal conduction to the LEDs depends on the specification of the reflow machine, and the size and layout of the PWBs, please check your solder conditions carefully.





#### 7-3. Cleaning

·Please use the soldering paste without need of cleaning.

· If the PCB needs cleaning, please follow the recommended conditions of ultrasonic cleaning.

①Recommended Conditions: R.T. 40kHz, 30W/l, 3 to 5 minutes
②Recommended Solvents: Water, methyl alcohol, ethyl alcohol, or isopropyl alcohol

The affect on the device depends on the conditions such as the size of ultrasonic bath, ultrasonic output, duration, the size of PCB and device mounting method.

Please check and test the cleaning method under the actual conditions before use.